SCS212AGHR

Automotive Grade SiC Schottky Barrier Diode

Datasheet

V_R	650V
I _F	12A
Q_{C}	18nC

Outline TO-220AC (1) (2) (3)

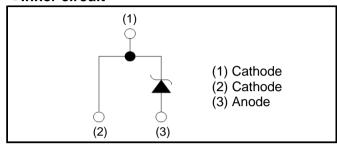
Features

- 1) AEC-Q101 qualified
- 2) Low forward voltage
- 3) Negligible recovery time/current
- 4) Temperature independent switching behavior

Applications

- · On Board Charger
- DC/DC Converter
- · Wireless Charger
- EV Charger

•Inner circuit



Packaging specifications

	Packaging	Tube
	Reel size (mm)	-
Tuno	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	50
	Packing code	С
	Marking	SCS212AG

• Absolute maximum ratings $(T_i = 25^{\circ}C)$

Parameter		Symbol	Value	Unit
Reverse voltage (re	epetitive peak)	V_{RM}	650	V
Reverse voltage (D	C)	V_{R}	650	V
Continuous forward	d current (T _c = 135°C)	I _F	12	А
Surge non-			43	А
repetitive forward	PW=10ms sinusoidal, T _j =150°C	I_{FSM}	34	А
current	PW=10μs square, T _j =25°C		170	А
Repetitive peak forward current		I _{FRM}	52 *1	А
PW=10ms, T _j =25°C		ر رو ر	9.2	A ² s
i ² t value	PW=10ms, T _j =150°C	$\int i^2 dt$	5.7	A ² s
Total power dissipation		P_{D}	93 *2	W
Junction temperature		T _j	175	°C
Range of storage temperature		T _{stg}	-55 to +175	°C

^{*1} T_c=100°C, T_i=150°C, Duty cycle=10% *2 T_c=25°C

•Electrical characteristics $(T_j = 25^{\circ}C)$

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =2.4mA	650	-	-	V
	V _F	I _F =12A,T _j =25°C	-	1.35	1.55	V
Forward voltage		I _F =12A,T _j =150°C	-	1.55	-	V
		I _F =12A,T _j =175°C	-	1.63	-	V
Reverse current	I _R	V _R =600V,T _j =25°C	-	2.4	240	μΑ
		V _R =600V,T _j =150°C	-	36	-	μΑ
		V _R =600V,T _j =175°C	-	84	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	440	-	pF
		V _R =600V,f=1MHz	-	44	-	pF
Total capacitive charge	Q _C	V _R =400V,di/dt=350A/μs	-	18	-	nC
Switching time	t _C	V _R =400V,di/dt=350A/μs	-	16	-	ns

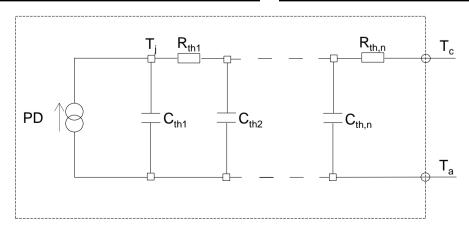
●Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	UIIIL
Thermal resistance	$R_{\text{th(j-c)}}$	-	ı	1.3	1.6	°C/W

● Typical Transient Thermal Characteristics

Symbol	Value	Unit
R _{th1}	3.70E-01	
R _{th2}	9.23E-01	K/W
R _{th3}	2.06E-03	

Symbol	Value	Unit
C_{th1}	1.98E-03	
C_{th2}	6.54E-03	Ws/K
C_{th3}	1.96E+00	



•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics

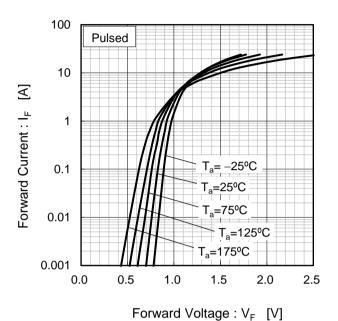
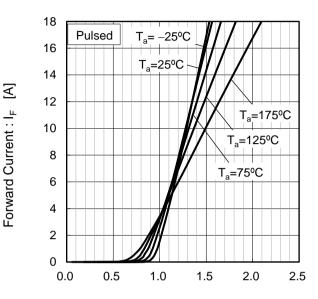


Fig.2 V_F - I_F Characteristics



Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics

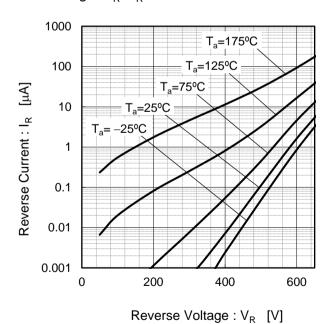
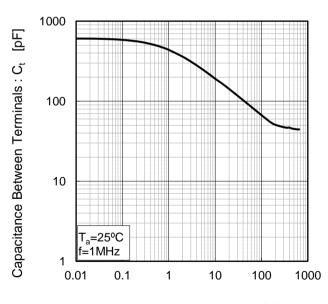


Fig.4 V_R - C_t Characteristics



Reverse Voltage : V_R [V]

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• Electrical characteristic curves

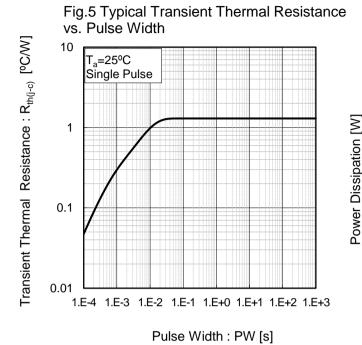


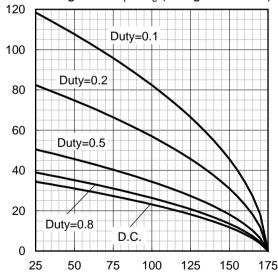
Fig.6 Power Dissipation 100 90 80 70 60 50 40 30 20 10 175 25 50 75 100 125 150

Fig.7*3 Maximum peak forward current derating curve I_P - T_C 120 100 Peak Forward Current : Ip [A] Duty=0.1 80 Duty=0.2 60 40 Duty=0.5 20 Duty=0.8 D.C. 0 25 50 75 100 125 150 175

Case Temperature : T_c [°C] *3 Based on max Vf, max $R_{th(j-c)}$ Valid for switching of above 10kHz, excluding D.C. curve.

Fig.8*4 Typical peak forward current derating curve I_P - T_c (Not guaranteed)

Case Temperature : T_c [°C]



Case Temperature : T_c [°C] *4 Based on typ Vf, typ R_{th(j-c)} Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

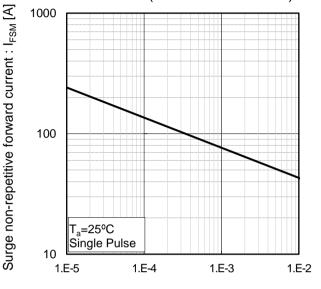
Peak Forward Current : Ip [A]

Capacitance stored energy : E_C[പ്വ]

•Electrical characteristic curves

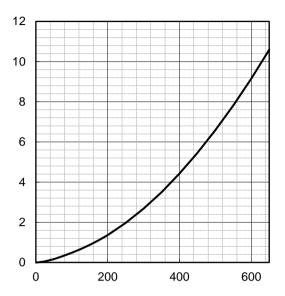
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Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)



Pulse Width: PW [s]

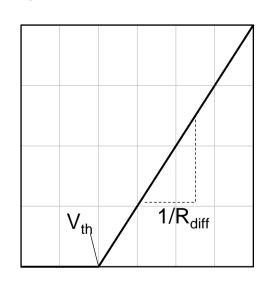
Fig.10 Typical capacitance store energy



Reverse Voltage: V_R [V]

Symplified forward characteristic model

Fig.11 Equivalent forward current curve



Forward Voltage : $V_{\rm F}$

$$V_F = V_{th} + R_{diff} I_F$$

$$V_{th} (T_j) = a_0 + a_1 T_j$$

 $R_{diff} (T_j) = b_0 + b_1 T_j + b_2 T_j^2$

Symbol	Typical Value	Unit
a ₀	9.35E-01	V
a ₁	-1.12E-03	V/°C
b ₀	3.32E-02	Ω
b ₁	8.50E-05	Ω/°C
b ₂	9.00E-07	Ω /°C ²

 T_i in °C; -55 °C < T_i < °C; I_F < 24 A

Forward Current: IF

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